



LTC1150

$\pm 15V$ Chopper Stabilized Operational Amplifier with Internal Capacitors

FEATURES

- High Voltage Operation, $\pm 18V$
- No External Components Required
- Maximum Offset Voltage $5\mu V$
- Maximum Offset Voltage Drift $0.05\mu V/^{\circ}C$
- Low Noise $1.8\mu V_{p-p}$ (0.1Hz to 10Hz)
- Minimum Voltage Gain 140dB
- Minimum PSRR 120dB
- Minimum CMRR 120dB
- Low Supply Current 0.8mA
- Single Supply Operation 4.75V to 36V
- Input Common Mode Range Includes Ground
- 200 μA Supply Current with Pin 1 Grounded
- Typical Overload Recovery Time 20ms

APPLICATIONS

- Strain Gauge Amplifiers
- Electronic Scales
- Medical Instrumentation
- Thermocouple Amplifiers
- High Resolution Data Acquisition

DESCRIPTION

The LTC1150 is a high-voltage, high-performance chopper stabilized operational amplifier. The two sample-and-hold capacitors usually required externally by other chopper amplifiers are integrated on-chip. Further, LTC's proprietary high-voltage CMOS structures allow the LTC1150 to operate at up to 36V total supply voltage.

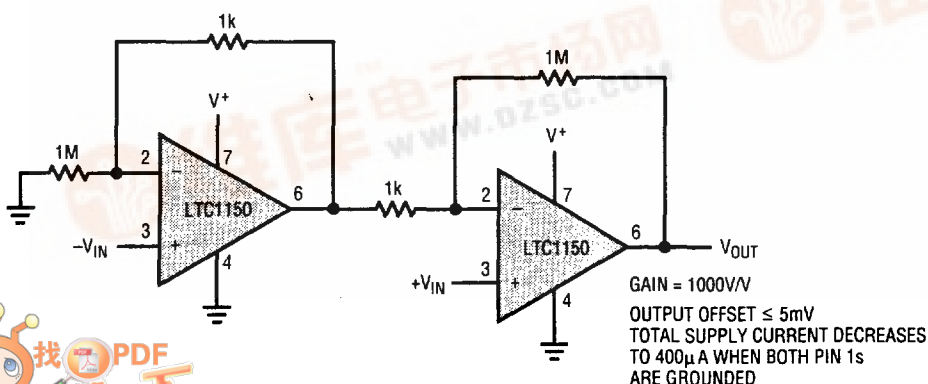
The LTC1150 has an offset voltage of $0.5\mu V$, drift of $0.01\mu V/^{\circ}C$, 0.1Hz to 10Hz input noise voltage of $1.8\mu V_{p-p}$ and a typical voltage gain of 180dB. The slew rate of 3V/ μs and a gain bandwidth product of 2.5MHz are achieved with 0.8mA of supply current. Overload recovery times from positive and negative saturation conditions are 3ms and 20ms, respectively.

For applications demanding low power consumption, pin 1 can be used to program the supply current. Pin 5 is an optional AC-coupled clock input, useful for synchronization.

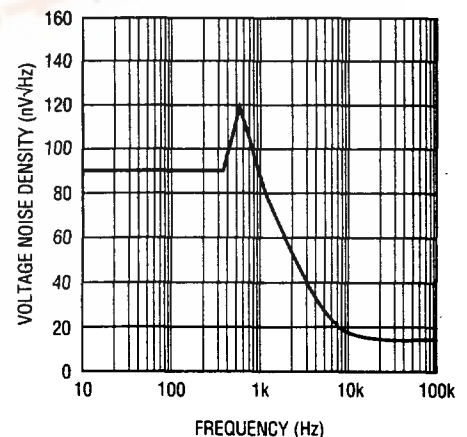
The LTC1150 is available in a standard 8-lead metal can, plastic and ceramic dual in line packages, as well as an 8-lead SO8 package. The LTC1150 can be a plug-in replacement for most standard bipolar op amps with significant improvement in DC performance.

TYPICAL APPLICATION

Single Supply Instrumentation Amplifier



Noise Spectrum



LTC1150 - TA01

LTC1150 - TPC26

LTC1150

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V^+ to V^-)	36V
Input Voltage (Note 2) ($V^+ + 0.3V$) to ($V^- - 0.3V$)	
Output Short Circuit Duration	Indefinite
Burn-In Voltage	36V
Operating Temperature Range	
LTC1150M	-55°C to 125°C
LTC1150C	-40°C to 85°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.)	300°C

PACKAGE/ORDER INFORMATION

TOP VIEW		ORDER PART NUMBER
<p>J8 PACKAGE 8-LEAD CERAMIC DIP</p> <p>N8 PACKAGE 8-LEAD PLASTIC DIP</p>		LTC1150MJ8 LTC1150CJ8 LTC1150CN8
TOP VIEW		LTC1150CS8
<p>S8 PACKAGE 8-LEAD PLASTIC SOIC</p>		
		S8 PART MARKING
		1150

ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$, Pin 1 = Open, T_A = Operating Temperature Range, unless otherwise specified.

PARAMETER	CONDITIONS		LTC1150M			LTC1150C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	$T_A = 25^\circ C$ (Note 3)		± 0.5	± 5		± 0.5	± 5		μV
Average Input Offset Drift	(Note 3)	•	± 0.01	± 0.05		± 0.01	± 0.05		$\mu V/^\circ C$
Long Term Offset Voltage Drift			50			50			nV/ \sqrt{mo}
Input Offset Current	$T_A = 25^\circ C$	•	± 20	± 60		± 20	± 200		pA
				± 1.5			± 0.5		nA
Input Bias Current	$T_A = 25^\circ C$	•	± 10	± 50		± 10	± 100		pA
				± 2.5			± 0.5		nA
Input Noise Voltage	$R_S = 100\Omega$, 0.1Hz to 10Hz, TC2		1.8			1.8			$\mu Vp-p$
	$R_S = 100\Omega$, 0.1Hz to 1Hz, TC2		0.6			0.6			
Input Noise Current	$f = 10Hz$ (Note 4)		1.8			1.8			fA/ \sqrt{Hz}
Common-Mode Rejection Ratio	$V_{CM} = V^-$ to 12V	•	110	130		110	130		dB
Power Supply Rejection Ratio	$V_S = \pm 2.375V$ to $\pm 16V$	•	120	145		120	145		dB
Large Signal Voltage Gain	$R_L = 10k\Omega$, $V_{OUT} = \pm 10V$	•	140	180		140	180		dB
Maximum Output Voltage Swing	$R_L = 10k\Omega$, $T_A = 25^\circ C$		± 13.5	± 14.5		± 13.5	± 14.5		V
	$R_L = 10k\Omega$	•	+ 10.5/ - 13.5			+ 10.5/ - 13.5			
	$R_L = 100k\Omega$		± 14.95			± 14.95			
Slew Rate	$R_L = 10k\Omega$, $C_L = 50pF$		3			3			V/ μs
Gain Bandwidth Product			2.5			2.5			MHz
Supply Current	No Load, $T_A = 25^\circ C$		0.8	1.0		0.8	1.5		mA
	No Load, Pin 1 = V^- , $T_A = 25^\circ C$		0.2			0.2			
	No Load	•		1.5			2		
Internal Sampling Frequency			550			550			Hz

ELECTRICAL CHARACTERISTICS

$V_S = 5V$, Pin 1 = Open, T_A = Operating Temperature Range, unless otherwise specified.

PARAMETER	CONDITIONS		LTC1150M			LTC1150C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	$T_A = 25^\circ\text{C}$ (Note 3)			± 0.5	± 5		± 0.05	± 5	μV
Average Input Offset Drift	(Note 3)	•		± 0.01	± 0.05		± 0.01	± 0.05	$\mu\text{V}/^\circ\text{C}$
Long Term Offset Voltage Drift				50			50		$\text{nV}/\sqrt{\text{mo}}$
Input Offset Current	$T_A = 25^\circ\text{C}$	•		± 10	± 30 ± 100		± 10	± 60 ± 100	pA
Input Bias Current	$T_A = 25^\circ\text{C}$	•		± 5	± 15 ± 400		± 5	± 30 ± 100	pA
Input Noise Voltage	$R_S = 100\Omega$, 0.1Hz to 10Hz, TC2			2.0			2.0		$\mu\text{Vp-p}$
	$R_S = 100\Omega$, 0.1Hz to 1Hz, TC2			0.7			0.7		
Input Noise Current	$f = 10\text{Hz}$ (Note 4)			1.3			1.3		$\text{fA}/\sqrt{\text{Hz}}$
Common-Mode Rejection Ratio	$V_{\text{CM}} = 0\text{V}$ to 2.7V	•	110			110			dB
Power Supply Rejection Ratio	$V_S = \pm 2.375\text{V}$ to $\pm 16\text{V}$	•	130	145		125	145		dB
Large Signal Voltage Gain	$R_L = 10\text{k}\Omega$, $V_{\text{OUT}} = 0.3\text{V}$ to 4.5V	•	130	180		130	180		dB
Maximum Output Voltage Swing	$R_L = 10\text{k}\Omega$			0.15 – 4.85			0.15 – 4.85		V
	$R_L = 100\text{k}\Omega$			0.02 – 4.97			0.02 – 4.97		
Slew Rate	$R_L = 10\text{k}\Omega$, $C_L = 50\text{pF}$			1.5			1.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product				1.8			1.8		MHz
Supply Current	No Load $T_A = 25^\circ\text{C}$	•		0.4	1 1.5		0.4	1 1.5	mA
Internal Sampling Frequency				300			300		Hz

The • denotes the specifications which apply over the full operating temperature range.

Note 1: Absolute Maximum Ratings are those values beyond which life of the device may be impaired.

Note 2: Connecting any terminal to voltages greater than V^+ or less than V^- may cause destructive latch-up. It is recommended that no sources operating from external supplies be applied prior to power-up of the LTC1150.

Note 3: These parameters are guaranteed by design. Thermocouple effects preclude measurement of these voltage levels in high-speed automatic test systems. V_{OS} is measured to a limit determined by test equipment capability.

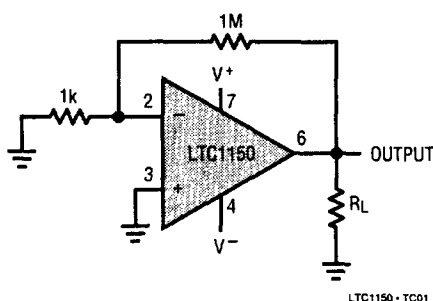
Note 4: Current Noise is calculated from the formula:

$$I_N = \sqrt{(2q \cdot I_b)}$$

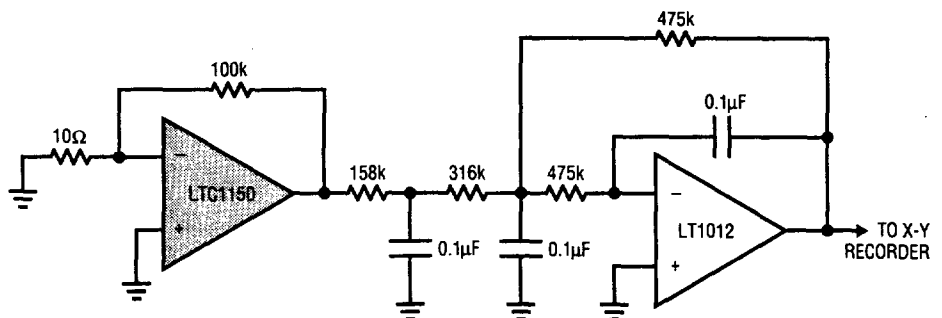
where $q = 1.6 \times 10^{-19}$ Coulomb.

TEST CIRCUITS

Offset Voltage Test Circuit



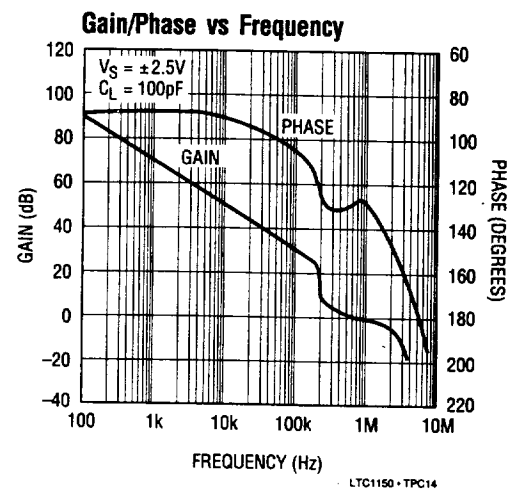
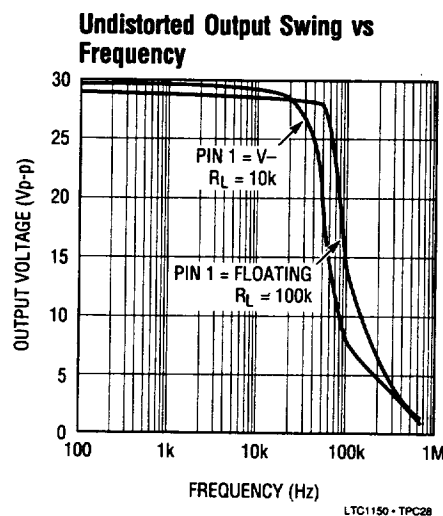
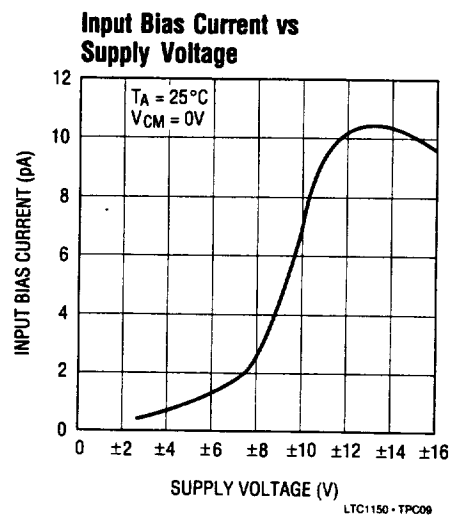
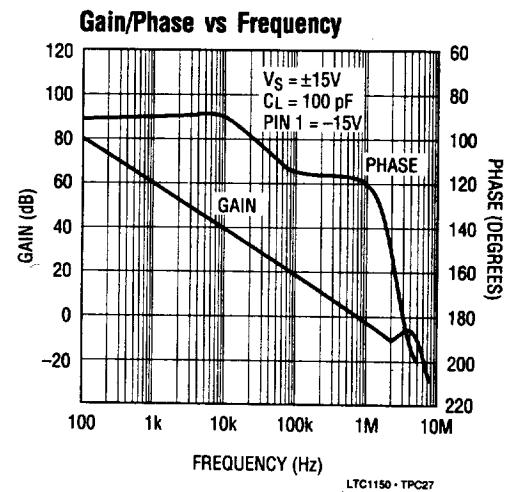
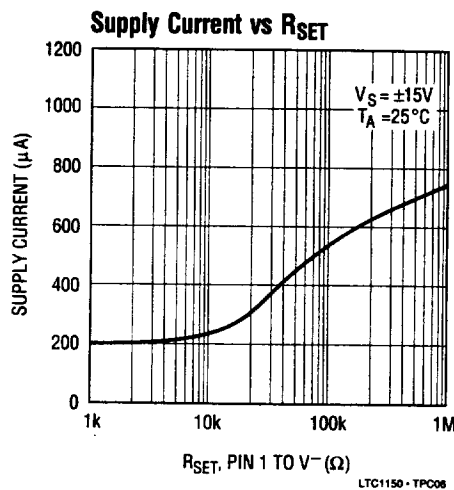
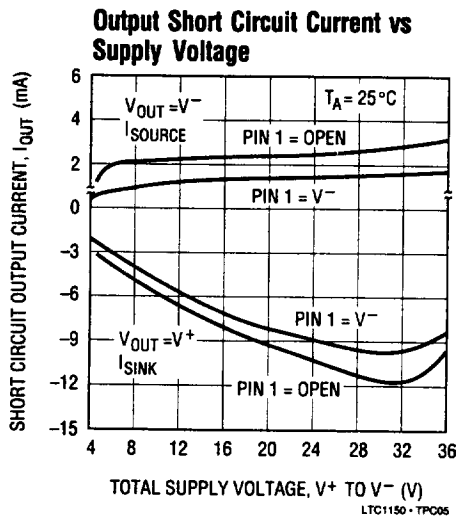
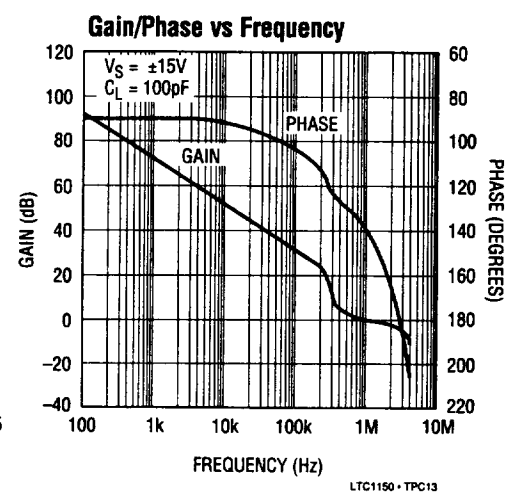
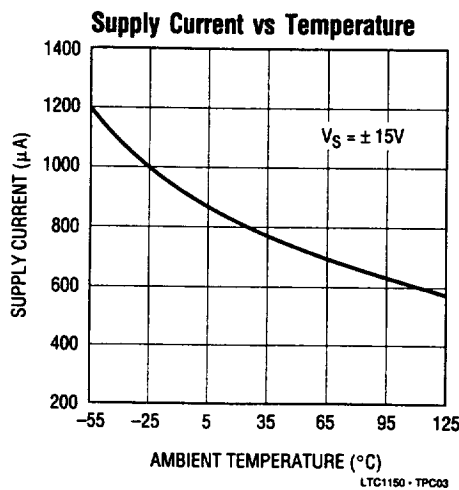
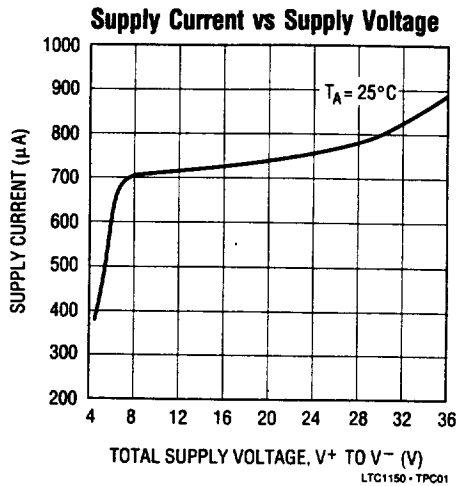
DC-10Hz Noise Test Circuit



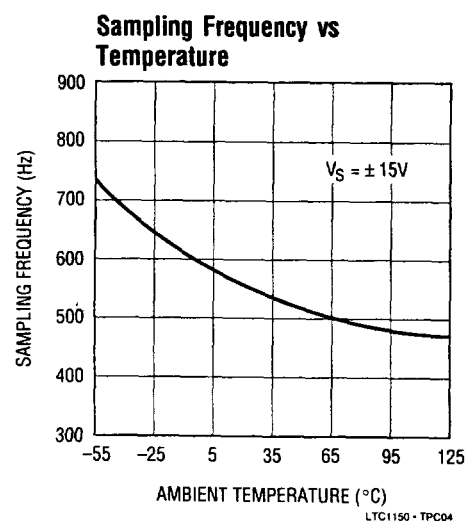
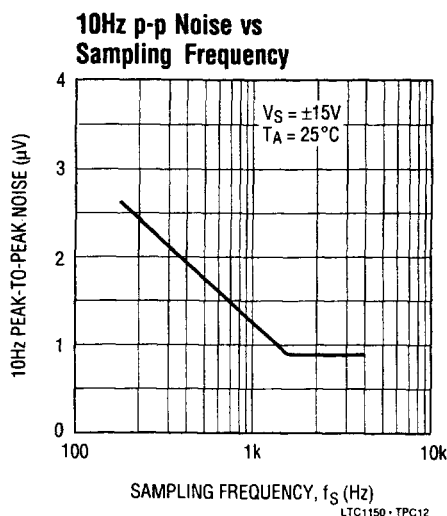
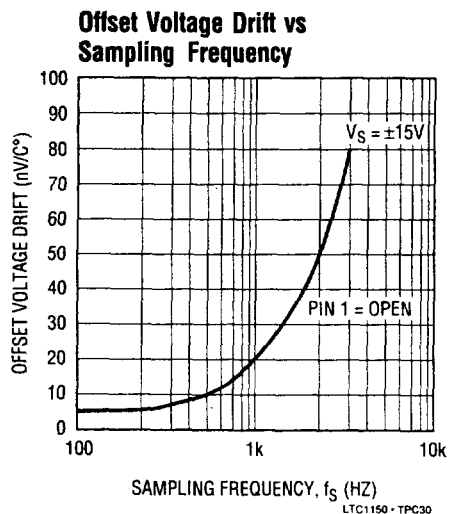
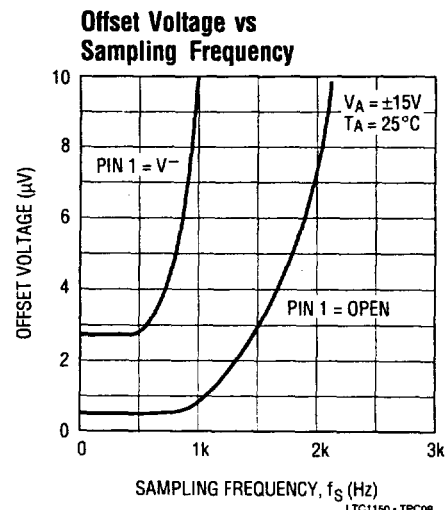
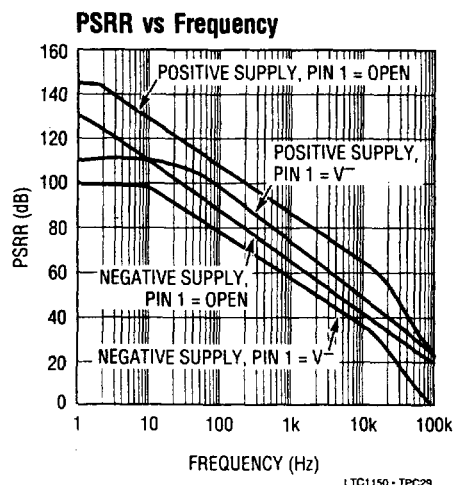
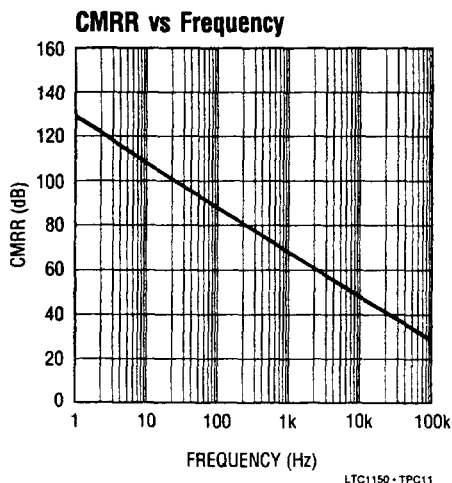
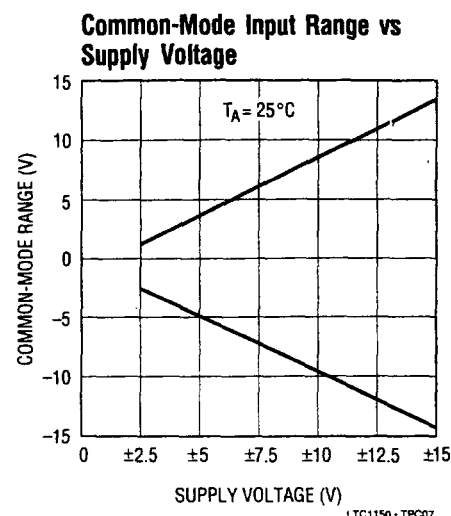
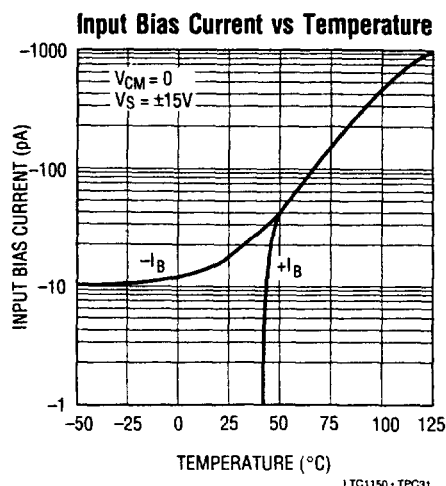
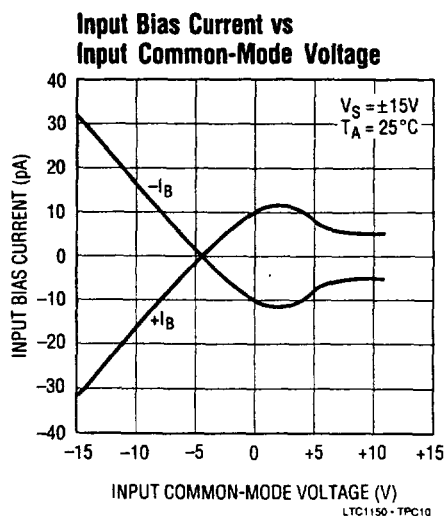
FOR 1Hz NOISE BW, INCREASE ALL THE CAPACITORS BY A FACTOR OF 10.

LTC1150

TYPICAL PERFORMANCE CHARACTERISTICS



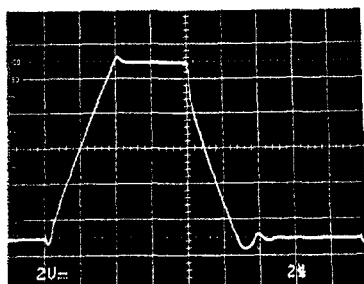
TYPICAL PERFORMANCE CHARACTERISTICS



LTC1150

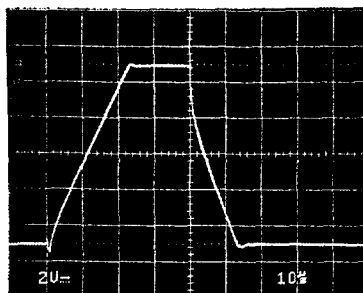
TYPICAL PERFORMANCE CHARACTERISTICS

Large Signal Transient Response



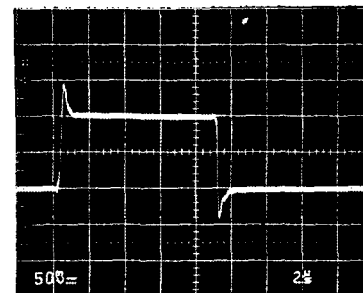
$V_S = \pm 15V$, $A_V = 1$, $C_L = 100pF$, $R_L = 10k\Omega$
LTC1150 - TPC15

Large Signal Transient Response, Pin 1 = V^-



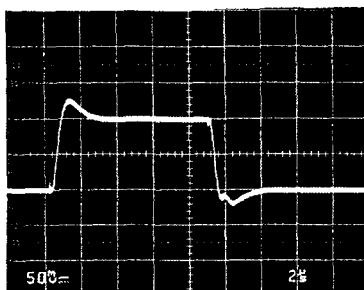
$V_S = \pm 15V$, $A_V = 1$, $C_L = 100pF$, PIN 1 = V^-
LTC1150 - TPC16

Small Signal Transient Response



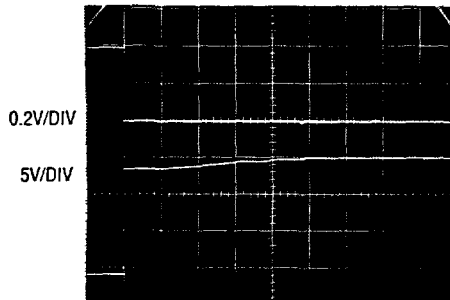
$V_S = \pm 15V$, $A_V = 1$, $C_L = 100pF$, $R_L = 10k\Omega$
LTC1150 - TPC17

Small Signal Transient Response, Pin 1 = V^-



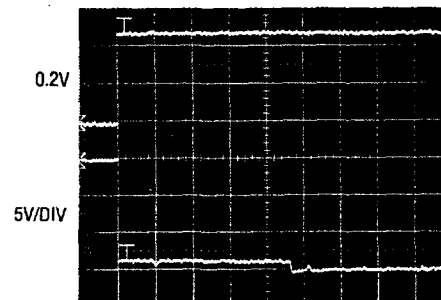
$V_S = \pm 15V$, $A_V = 1$, $C_L = 100pF$, $R_L = 10k\Omega$,
PIN 1 = V^-
LTC1150 - TPC18

Overload Recovery from Negative Saturation



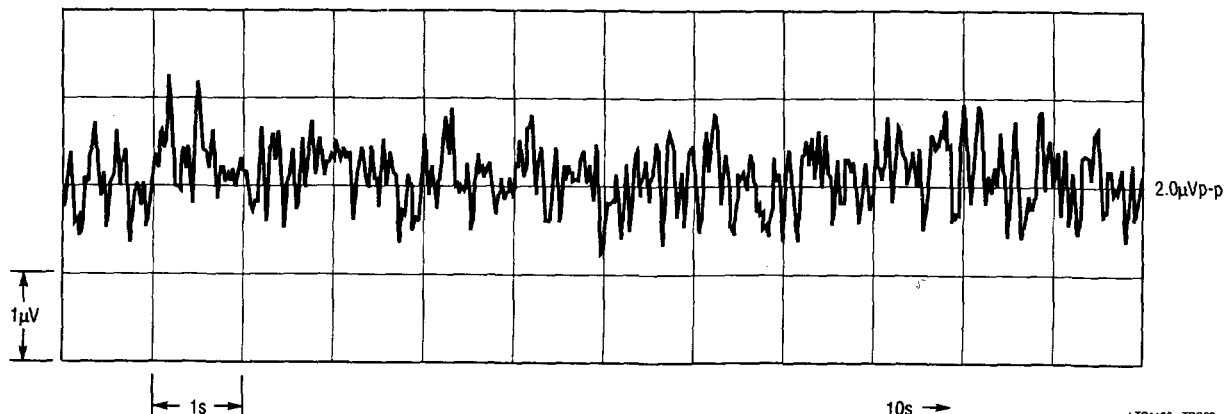
$V_S = \pm 15V$, $A_V = -100$, 2ms/DIV
LTC1150 - TPC21

Overload Recovery from Positive Saturation



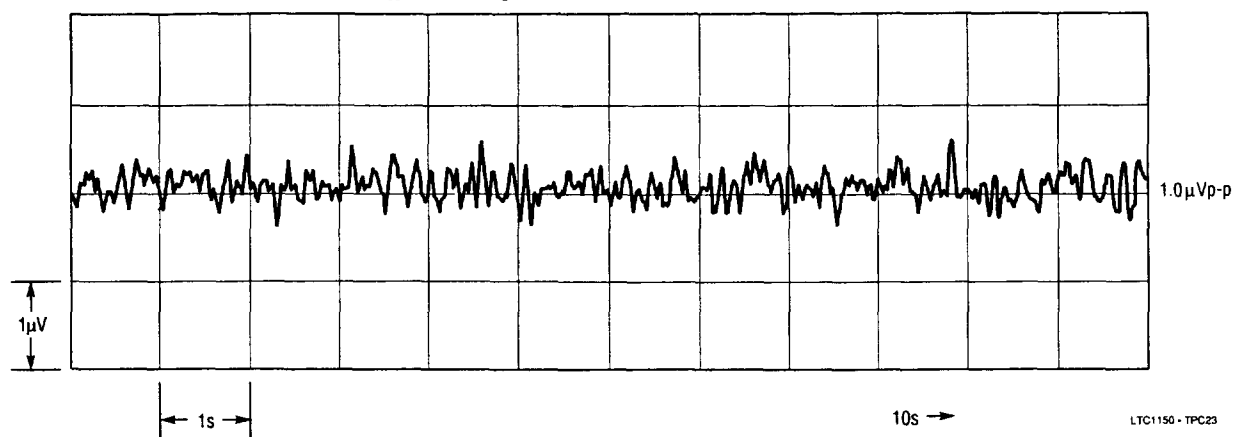
$V_S = \pm 15V$, $A_V = -100$, 2ms/DIV
LTC1150 - TPC33

0.1Hz-10Hz Noise, $V = \pm 15V$, $T_A = 25^\circ C$, Internal Clock

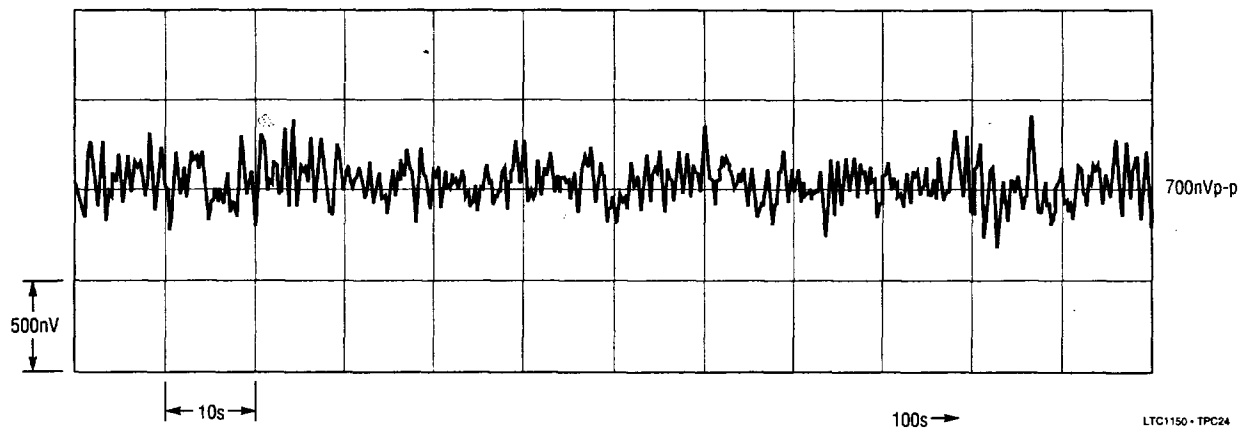
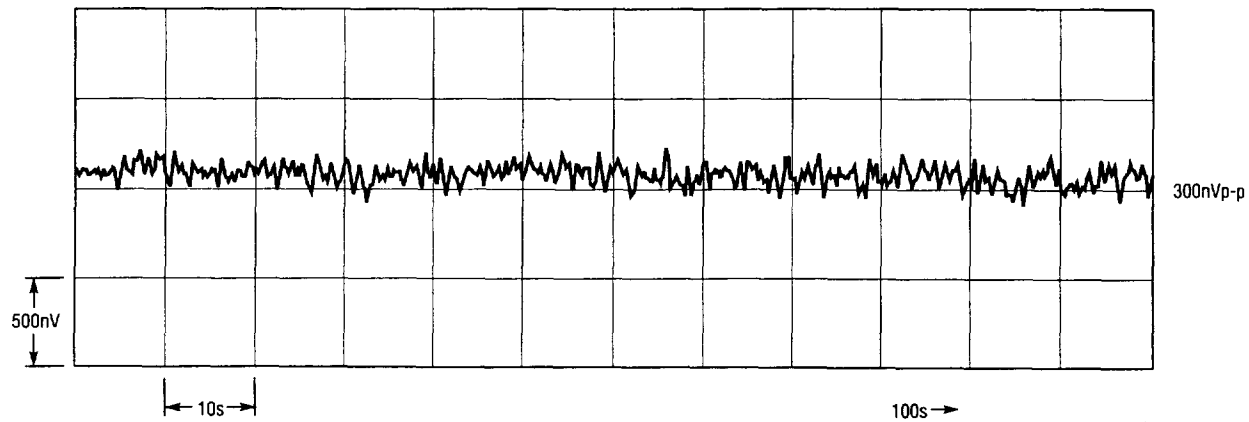


LTC1150 - TPC22

TYPICAL PERFORMANCE CHARACTERISTICS

0.1Hz-10Hz Noise, $V = \pm 15V$, $T_A = 25^\circ C$, $f_S = 1800Hz$ 

2

0.1Hz-1Hz Noise, $V = \pm 15V$, $T_A = 25^\circ C$, Internal Clock0.1Hz-1Hz Noise, $V = \pm 15V$, $T_A = 25^\circ C$, $f_S = 1800Hz$ 

PIN DESCRIPTIONS

1) 8-Pin Packages

Pin 1 – Supply Current Programming. The supply current can be programmed through pin 1. When pin 1 is left open or tied to $+V_S$, the supply current defaults to $800\mu A$. Tying a resistor between pin 1 and pin 4, the negative supply pin, will reduce the supply current. The supply current, as a function of the resistor value, is shown in Typical Performance Characteristics.

Pin 2 – Inverting Input.

Pin 3 – Non-Inverting Input.

Pin 4 – Negative Supply.

Pin 5 – Optional External Clock Input. The LTC1150 has an internal oscillator to control the circuit operation of the amplifier if pin 5 is left open or biased at any DC voltage in the supply voltage range. When an external clock is

desirable it can be applied to pin 5. The applied clock is AC-coupled to the internal circuitry to simplified interface requirements. The amplitude of clock input signal needs to be greater than 2V and the voltage level has to be within the supply voltage range. Duty cycle is not critical. The internal chopping frequency is the external clock frequency divided by four. When frequency of the external clock falls below 100Hz (internal chopping at 25Hz), the internal oscillator takes over and the circuit chops at 550Hz.

Pin 6 – Output.

Pin 7 – Positive Supply.

Pin 8 – Clock Output. The signal coming out of this pin is at the internal oscillator frequency of about 2.2kHz (four times the chopping frequency) and has voltage levels at $V_H = +V_S$ and $V_L = V_S - 4.6V$. If the circuit is driven by an external clock, pin 8 is pulled up to $+V_S$.

APPLICATIONS INFORMATION

ACHIEVING PICOAMPERE/MICROVOLT PERFORMANCE

Picoamperes

In order to realize the picoampere level of accuracy of the LTC1150, proper care must be exercised. Leakage currents in circuitry external to the amplifier can significantly degrade performance. High quality insulation should be used (e.g., Teflon, Kel-F); cleaning of all insulating surfaces to remove fluxes and other residues will probably be necessary – particularly for high temperature performance. Surface coating may be necessary to provide a moisture barrier in high humidity environments.

Board leakage can be minimized by encircling the input connections with a guard ring operated at a potential close to that of the inputs: in inverting configurations the guard ring should be tied to ground; in non-inverting connections to the inverting input. Guarding both sides of the printed circuit board is required. Bulk leakage reduction depends on the guard ring width.

Microvolts

Thermocouple effects must be considered if the LTC1150's ultra low drift is to be fully utilized. Any connection of dissimilar metals forms a thermoelectric junction producing an electric potential which varies with temperature (Seebeck effect). As temperature sensors, thermocouples exploit this phenomenon to produce useful information. In low drift amplifier circuits the effect is a primary source of error.

Connectors, switches, relay contacts, sockets, resistors, solder, and even copper wire are all candidates for thermal EMF generation. Junctions of copper wire from different manufacturers can generate thermal EMFs of $200nV/^\circ C$ — four times the maximum drift specification of the LTC1150. The copper/kovar junction, formed when wire or printed circuit traces contact a package lead, has a thermal EMF of approximately $35\mu V/^\circ C$ — 700 times the maximum drift specification of the LTC1150.

Minimizing thermal EMF-induced errors is possible if judicious attention is given to circuit board layout and

APPLICATIONS INFORMATION

component selection. It is good practice to minimize the number of junctions in the amplifier's input signal path. Avoid connectors, sockets, switches, and relays where possible. In instances where this is not possible, attempt to balance the number and type of junctions so that differential cancellation occurs. Doing this may involve deliberately introducing junctions to offset unavoidable junctions.

Figure 1 is an example of the introduction of an unnecessary resistor to promote differential thermal balance. Maintaining compensating junctions in close physical proximity will keep them at the same temperature and reduce thermal EMF errors.

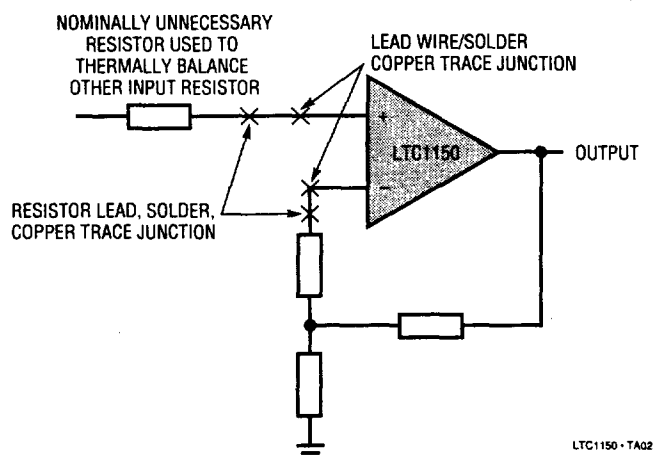


Figure 1. Extra Resistors Cancel Thermal EMF

When connectors, switches, relays and/or sockets are necessary they should be selected for low thermal EMF activity. The same techniques of thermally-balancing and coupling the matching junctions are effective in reducing the thermal EMF errors of these components.

Resistors are another source of thermal EMF errors. Table 1 shows the thermal EMF generated for different resistors. The temperature gradient across the resistor is important, not the ambient temperature. There are two junctions formed at each end of the resistor and if these junctions are at the same temperature, their thermal EMFs will cancel each other. The thermal EMF numbers are approximate and vary with resistor value. High values give higher thermal EMF.

Table 1. Resistor Thermal EMF

Resistor Type	Thermal EMF/°C Gradient
Tin Oxide	~mV/°C
Carbon Composition	~450μV/°C
Metal Film	~20μV/°C
Wire Wound Evenohm Manganin	~2μV/°C ~2μV/°C

PACKAGE-INDUCED OFFSET VOLTAGE

Package-induced thermal EMF effects are another important source of errors. It arises at the copper/kovar junctions formed when wire or printed circuit traces contact a package lead. Like all the previously mentioned thermal EMF effects, it is outside the LTC1150's offset nulling loop and cannot be cancelled. Metal can H packages exhibit the worst warm-up drift. The input offset voltage specification of the LTC1150 is actually set by the package-induced warm-up drift rather than by the circuit itself. The thermal time constant ranges from 0.5 to 3 minutes, depending on package type.

ALIASING

Like all sampled data systems, the LTC1150 exhibits aliasing behavior at input frequencies near the sampling frequency. The LTC1150 includes a high-frequency correction loop which minimizes this effect; as a result, aliasing is not a problem for most applications.

For a complete discussion of the correction circuitry and aliasing behavior, please refer to the LTC1051/53 data sheet.

SYNCHRONIZATION OF MULTIPLE LTC1150's

When synchronization of several LTC1150's is required, one of the LTC1150's can be used to provide the "master" clock to control over 100 "slave" LTC1150's. The master clock, coming from pin 8 of the master LTC1150, can directly drive pin 5 of the slaves. Note that pin 8 of the slave LTC1150's will be pulled up to +V_S.

If all the LTC1150's are to be synchronized with an external clock, then the external clock should drive pin 5 of all the LTC1150's.

LTC1150

APPLICATIONS INFORMATION

LEVEL SHIFTING THE CLOCK

Level shifting is needed if the clock output of the LTC1150 in $\pm 15\text{V}$ operation must interface to regular $+5\text{V}$ logic circuits. Figures 2 and 3 show some typical level shifting circuits.

When operated from a single $+5\text{V}$ or $\pm 5\text{V}$ supplies, the LTC1150 clock output at pin 8 can interface to TTL or CMOS inputs directly.

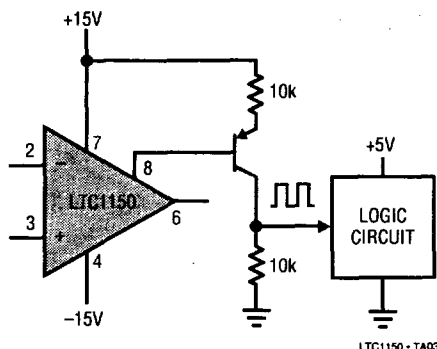


Figure 2. Output Level Shift (Option 1)

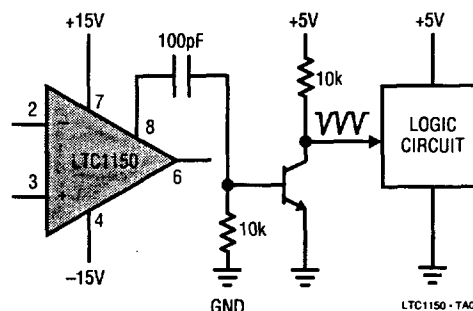
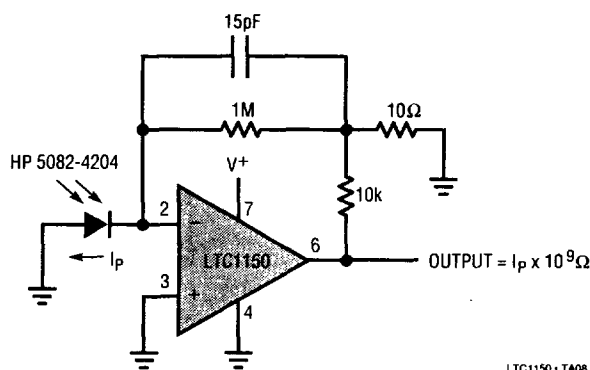


Figure 3. Output Level Shift (Option 2)

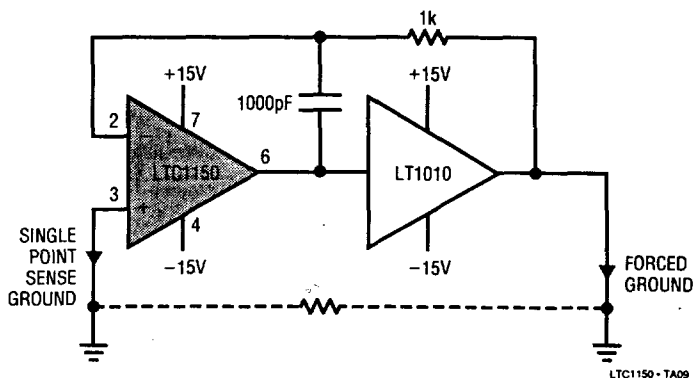
TYPICAL APPLICATIONS

Low Level Photodetector



LTC1150 - TA08

Ground Force Reference

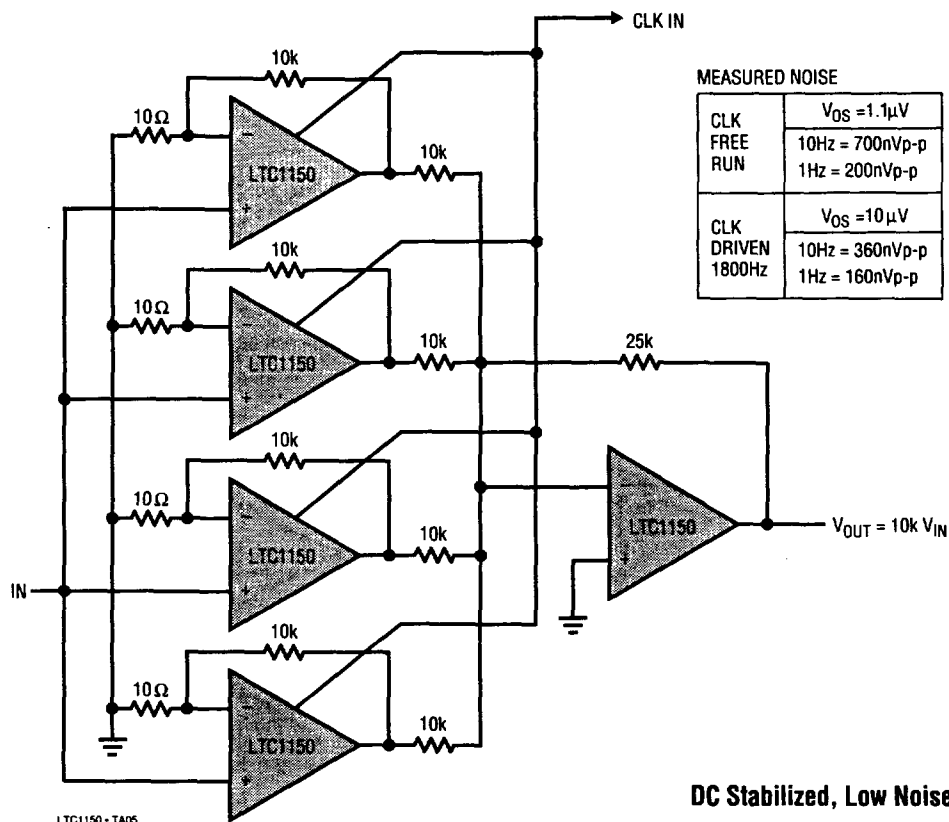


LTC1150 - TA09

APPLICATION: TO FORCE TWO GROUND POINTS IN A SYSTEM WITHIN $5\mu\text{V}$.

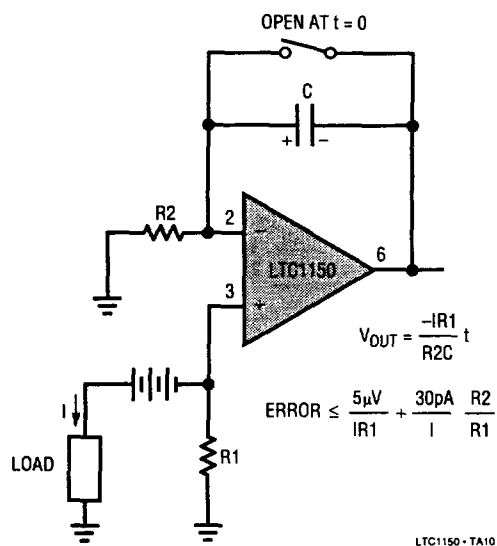
TYPICAL APPLICATIONS

Paralleling to Improve Noise



2

Battery Discharge Monitor



DC Stabilized, Low Noise Amplifier

